

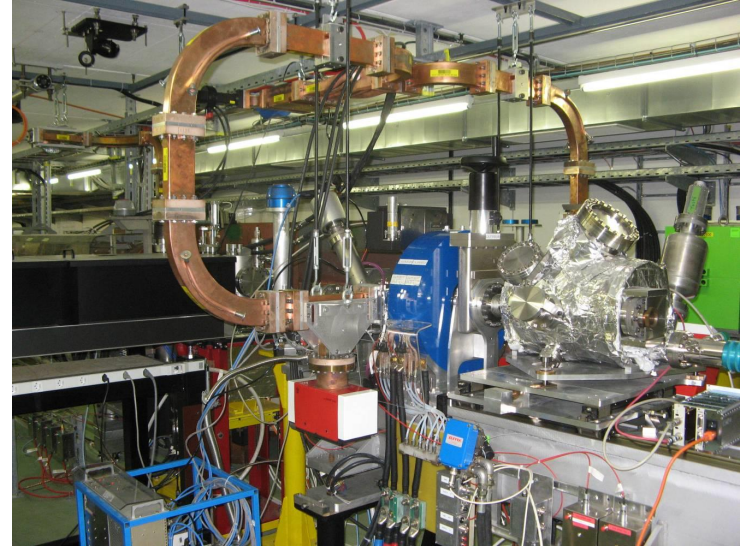


# Electron and Ion Sources

## Layout

- **Electron Sources**
  - Thermionic
  - Photo-Cathodes
- **Ion Sources**
  - Particle motion in plasmas
  - Protons
  - ECR Ion Source
  - Negative Ions

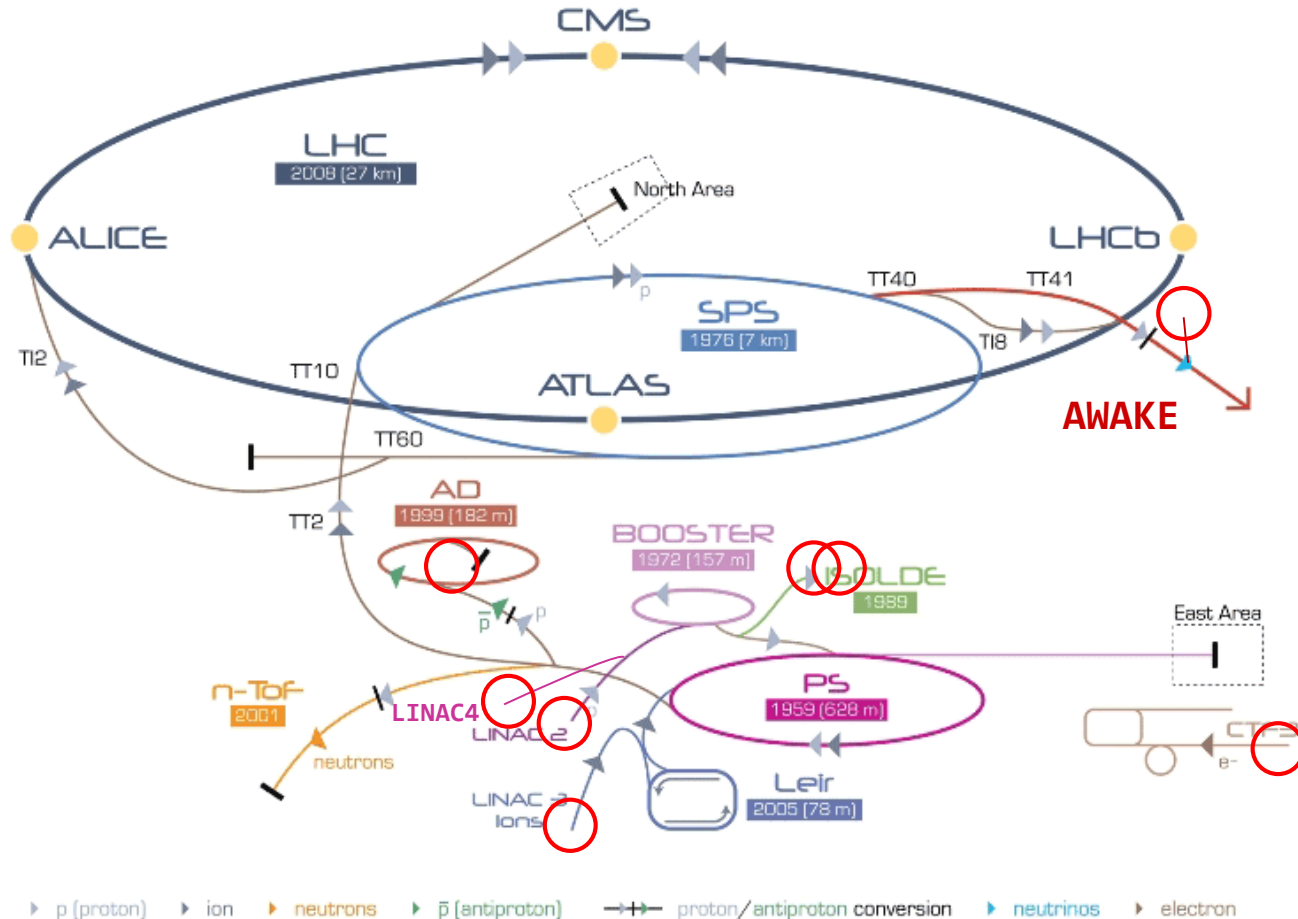
Richard Scrivens, BE Dept, CERN.  
CAS@CERN, June 2018





# Electron and Ion Sources

Every accelerator chain needs a source!

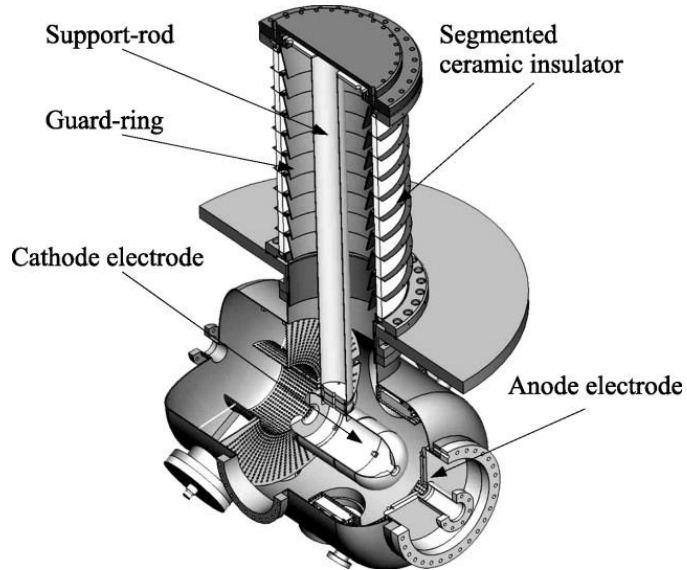


LHC Large Hadron Collider SPS Super Proton Synchrotron PS Proton Synchrotron  
 AD Antiproton Decelerator CTF-3 Clic Test Facility CNUS Cern Neutrinos to Gran Sasso ISOLDE Isotope Separator OnLine DEvice  
 LEIR Low Energy Ion Ring LINAC LInear ACcelerator n-ToF Neutrons Time Of Flight

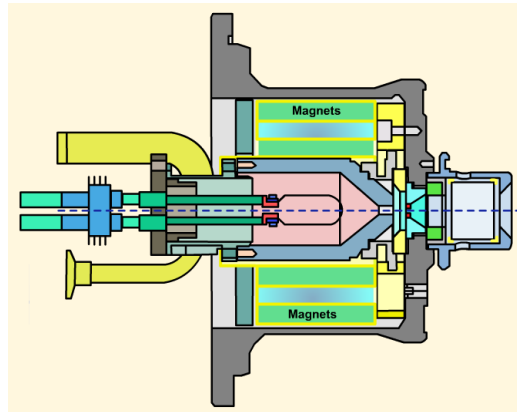


# Electron and Ion Sources

**Every accelerator chain needs a source!**

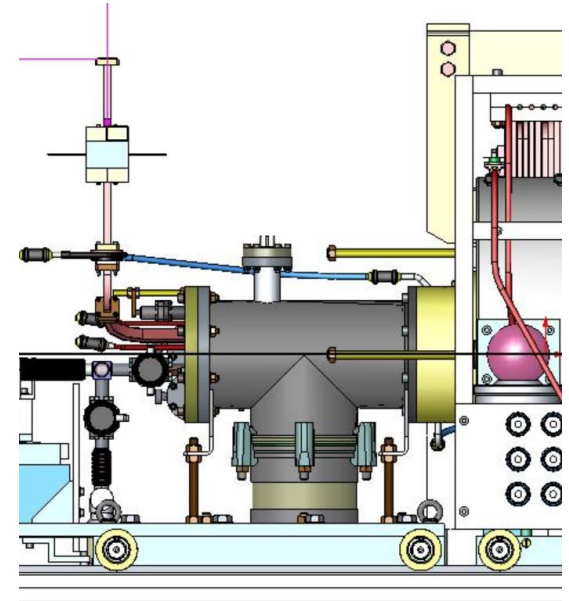


Principles of the electron guns, with thermionic and photo cathodes



Protons

Principles of ion sources, and the types used at CERN.



Ions



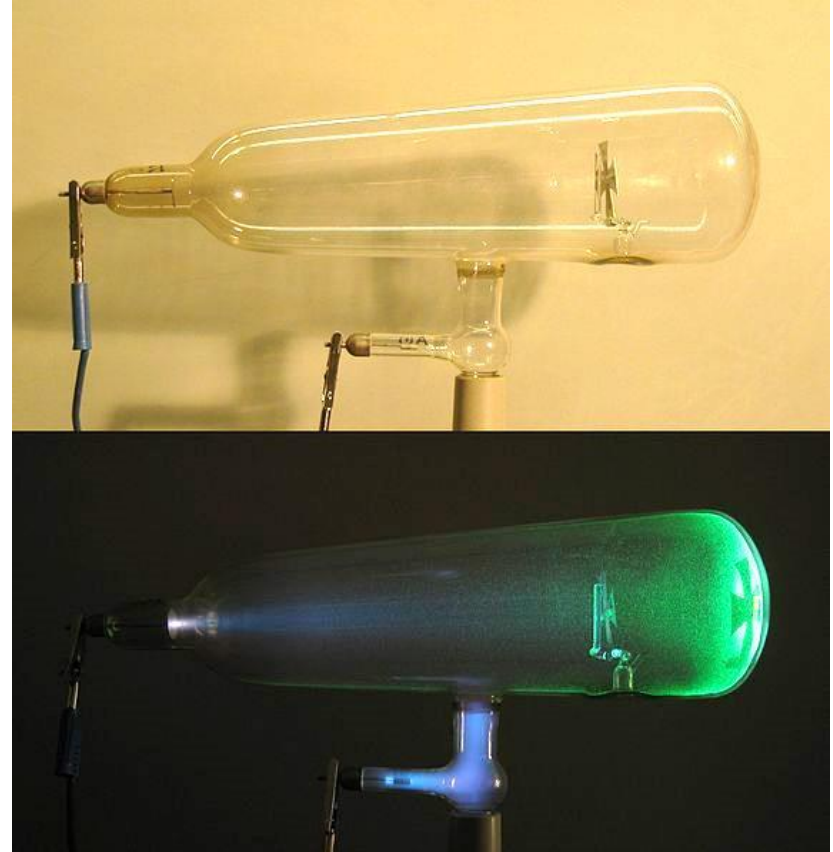
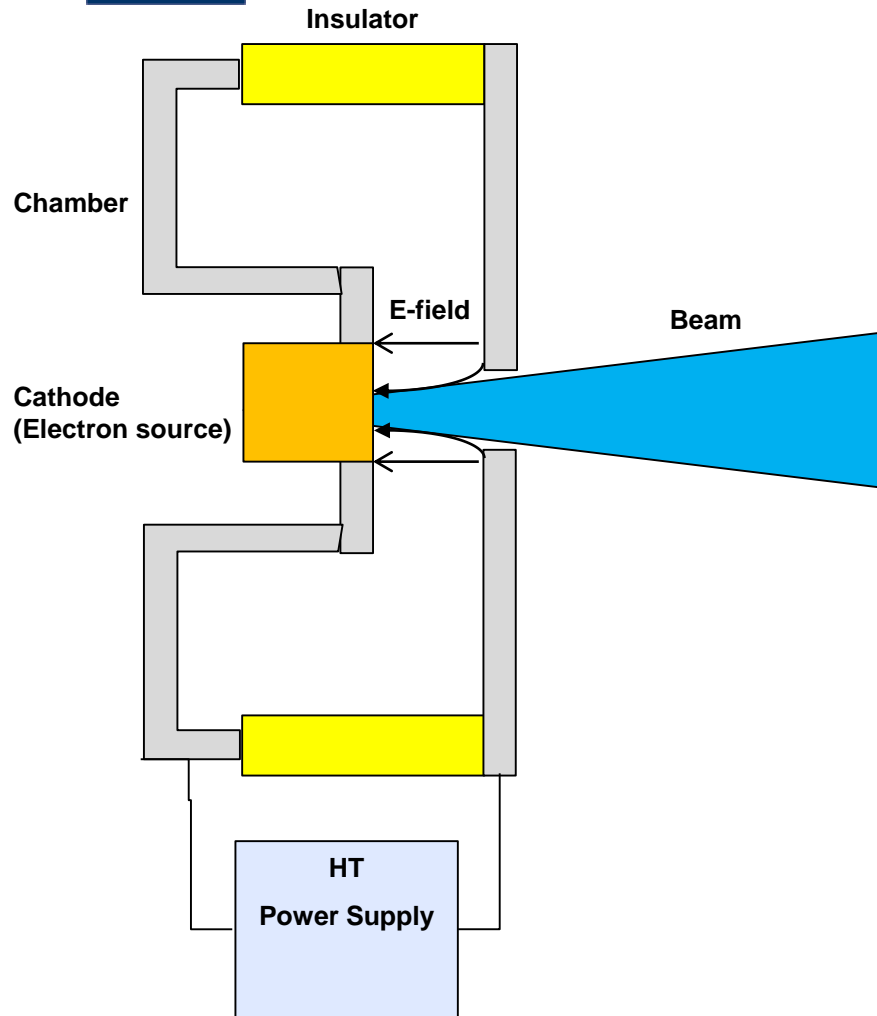
# Electron and Ion Sources

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# Electron and Ion Sources

## Electron Sources - Basics



The classic Cathode Ray Experiment



# Electron and Ion Sources

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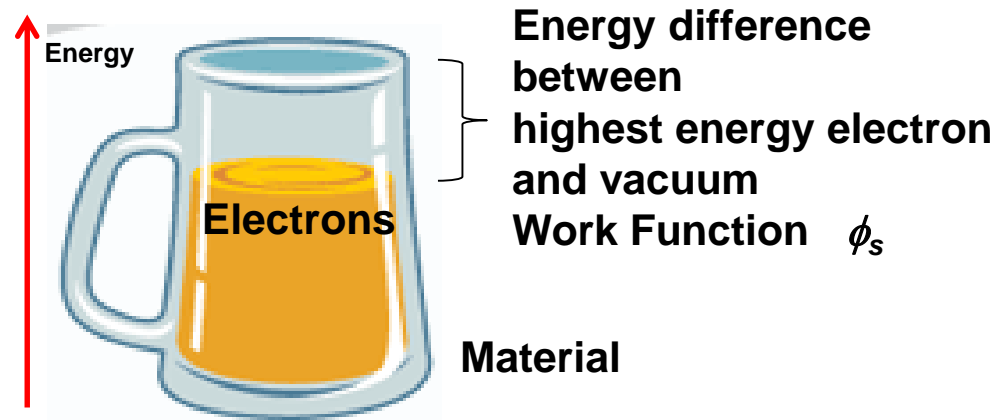


# Electron and Ion Sources

## Electrons – Thermionic Emission

Electrons within a material are heated to energies above that needed to escape the material.

Cathode emission is dominated by the Richardson Dushman equation.





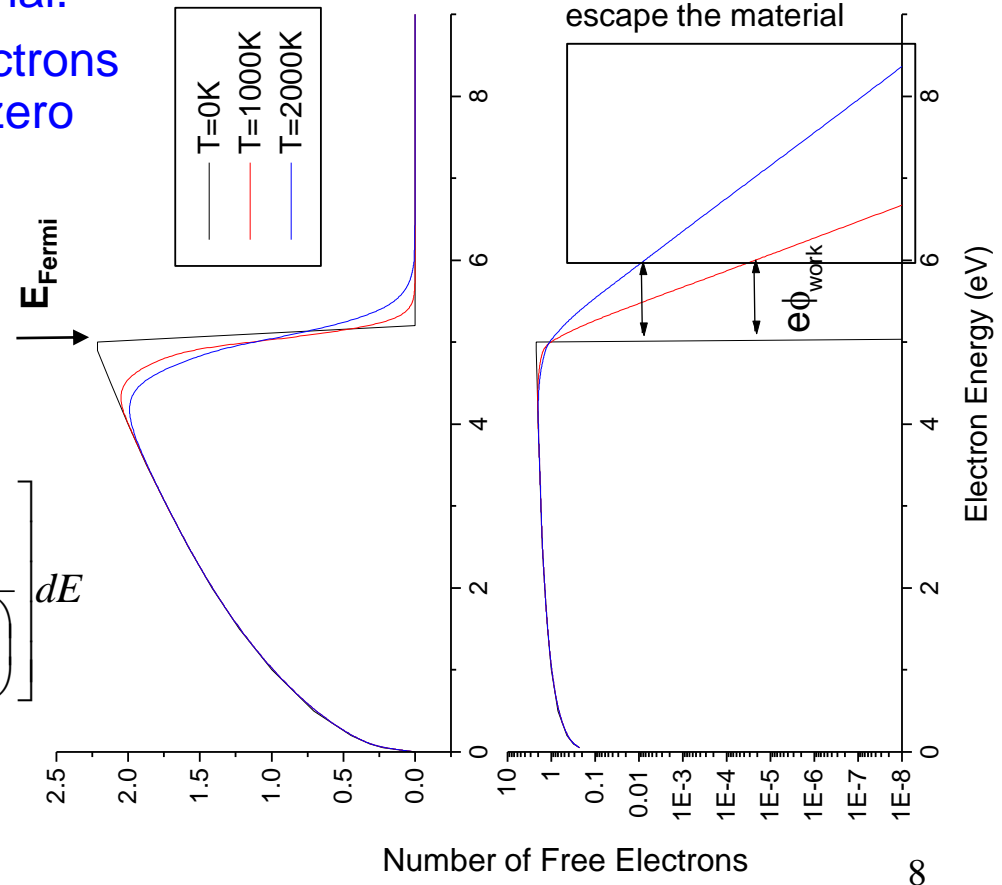
# Electron and Ion Sources

## Electrons – Thermionic Emission (the maths)

Conducting materials contain free electrons, who follow the Fermi-Dirac energy distribution inside the material.

When a material is heated, the electrons energy distribution shifts from the zero temperature Fermi distribution.

$$n(E)dE = \left[ \frac{4\pi(2m_e)^{3/2}}{h^3} \right] \left[ \frac{\sqrt{E}}{1 + \exp\left(\frac{E - E_{Fermi}}{kT}\right)} \right] dE$$







# Electron and Ion Sources

## Electrons – Thermionic Emission (the maths)

Therefore at high temperatures there is an ELECTRON CLOUD around the material. The current density can then be found by integrating the available electrons and their energy.

$$J = nev$$

$$J = A \cdot T^2 \exp\left(\frac{-eU_{work}}{kT}\right)$$

$$A = \frac{4\pi em_e k^2}{h^3} \approx 1.2 \times 10^6 \text{ Am}^{-2} \text{ K}^{-2}$$

This electron current is available to be pulled off the surface...  
Richardson-Dushman equation  
*Rev. Mod. Phys. 2, p382 (1930)*

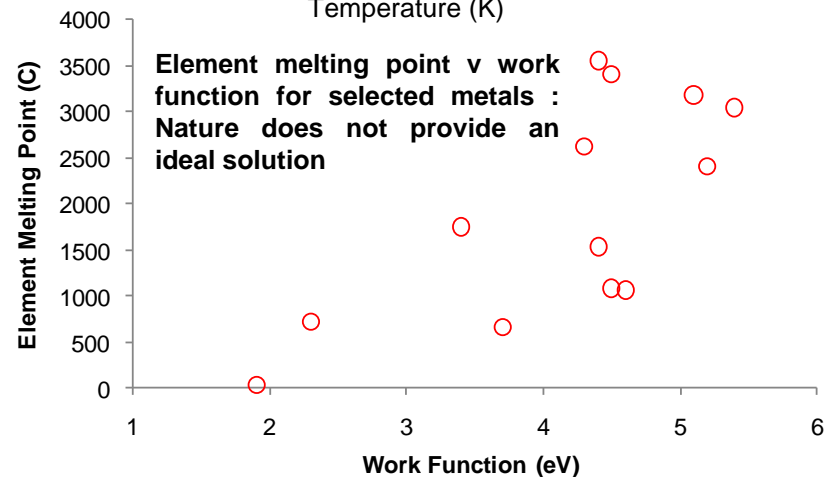
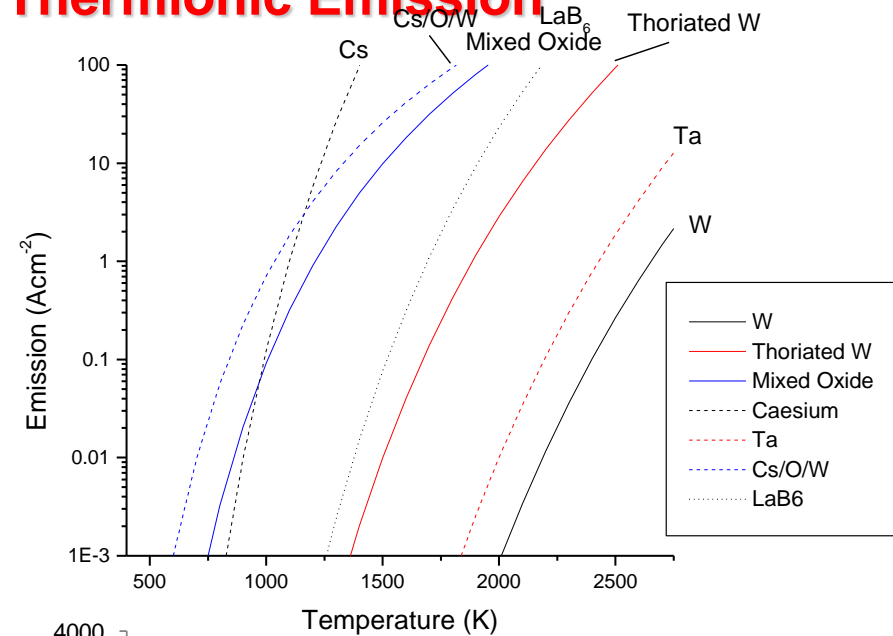
This factor  $A$  is not achieved in practice (some electrons are reflected from the inner surface)



# Electron and Ion Sources

## Electrons – Thermionic Emission

	$A$ $\text{Acm}^{-2}\text{K}^{-2}$	$U_{\text{work}}$ eV
W	60	4.54
W Thoriated	3	2.63
Mixed Oxide	0.01	1
Cesium	162	1.81
Ta	60	4.12
Cs/O/W	0.003*	0.72*
LaB <sub>6</sub>	29	2.66



\*- A and work function depend on the Cs/O lay  
Thickness and purity



# Electron and Ion Sources

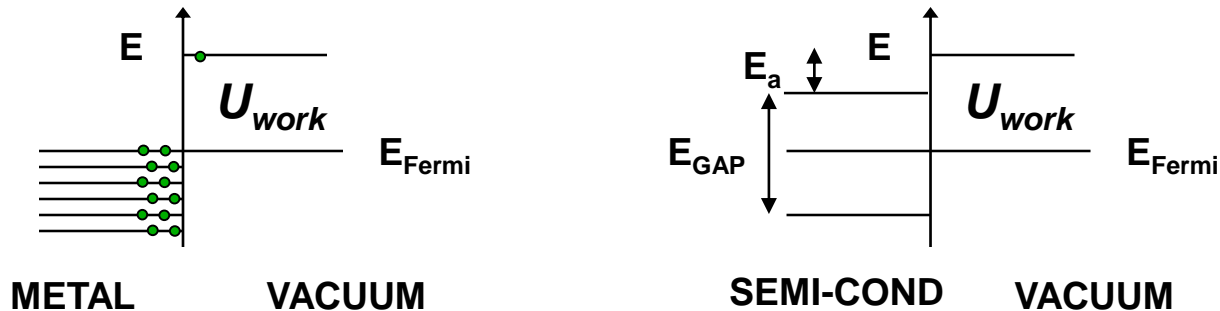
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# Electron and Ion Sources

## Electrons – Photo Emission

The energy of an electron in a material can be increased above the vacuum energy by absorbing photons - photoelectric effect.



$$\text{Photon Energy} = \frac{hc}{\lambda}$$

$$\lambda_c = \frac{hc}{eU_{\text{work}}} = \frac{1239.8}{U_{\text{work}}}$$

$$\lambda_c = \frac{hc}{E_{\text{GAP}} + E_a} = \frac{1239.8}{E_{\text{GAP}} + E_a}$$

	$U_{\text{work}}$ (eV)	$\lambda_c$ (nm)
W	4.5	275
Mg	3.67	340
Cu	4.65	267

	$E_g + E_a$ (eV)	$\lambda_c$ (nm)
GaAs	5.5	225
Cs <sub>2</sub> Te	~3.5	350
K <sub>2</sub> CsSb	2.1	590



# Electron and Ion Sources

## Electrons – Photo Cathodes

Quantum Efficiency = Electrons/photon [  $Q_e(\lambda)$  ]

GaAs:Cs=17% , CsTe=12.4% , K<sub>2</sub>CsSb=29%, Cu~0.01%,  
Strongly wavelength dependent.

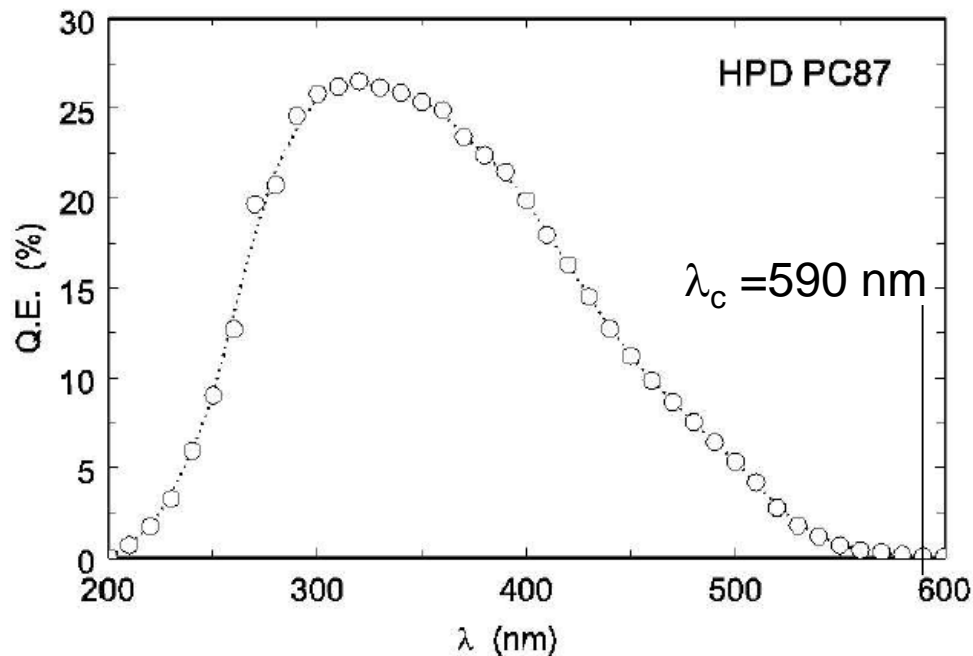


Figure 6. Quantum efficiency of a K<sub>2</sub>CsSb photo-cathode produced on a UV extended HPD glass window.



# Electron and Ion Sources

## Electrons – Photo Cathodes

- **METALS**

- Lower quantum efficiency requires high power lasers.
- But at high optical powers, a plasma is formed.
- Very robust and simple to use cathode material.

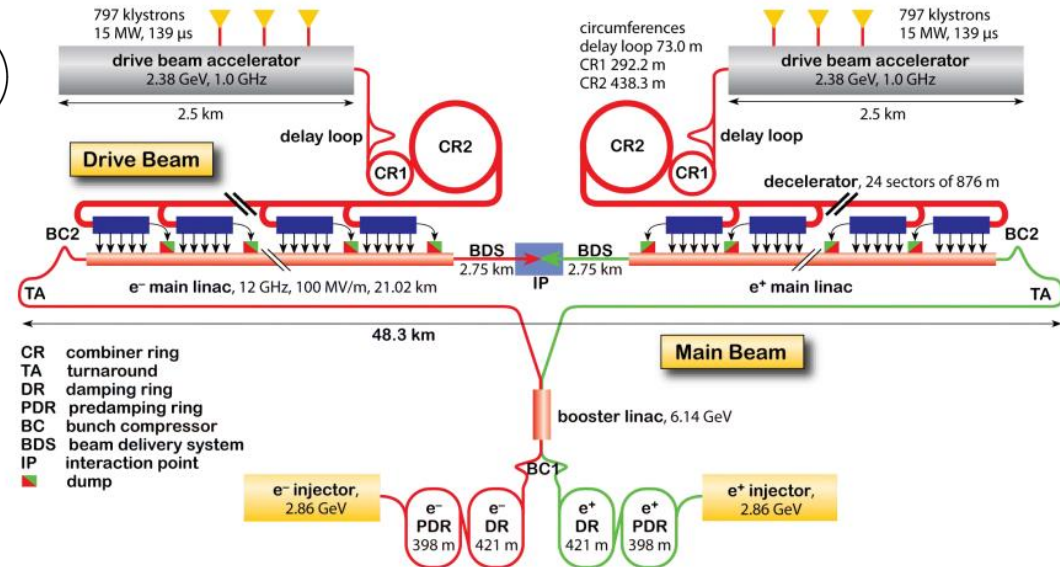
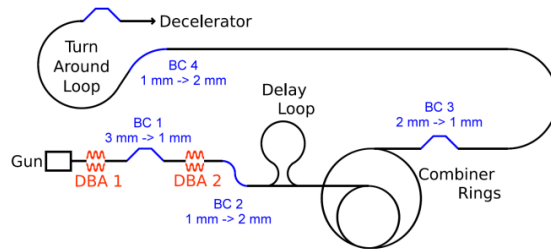
- **SEMICONDUCTORS**

- Can find materials optical wavelengths with high quantum efficiency (cf Photo Cathode Tubes).
- Difficult to use in a high radiation area of an electron-gun (x-rays and ions cause decomposition and surface damage).
- Cs<sub>2</sub>Te (Cesium Telluride) – High Quantum efficiency but needs UV lasers.



# Electron and Ion Sources

## CLIC – Electron Guns



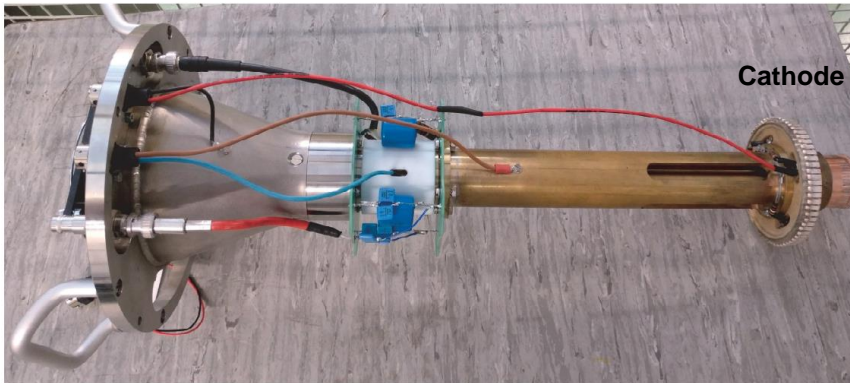
CTF3 has three electron guns.

1. A thermionic Gun for the drive beam generation
2. A test photo-emission and RF gun as a test facility for the drive beam.
3. A photo-emission and RF gun for the probe beam.

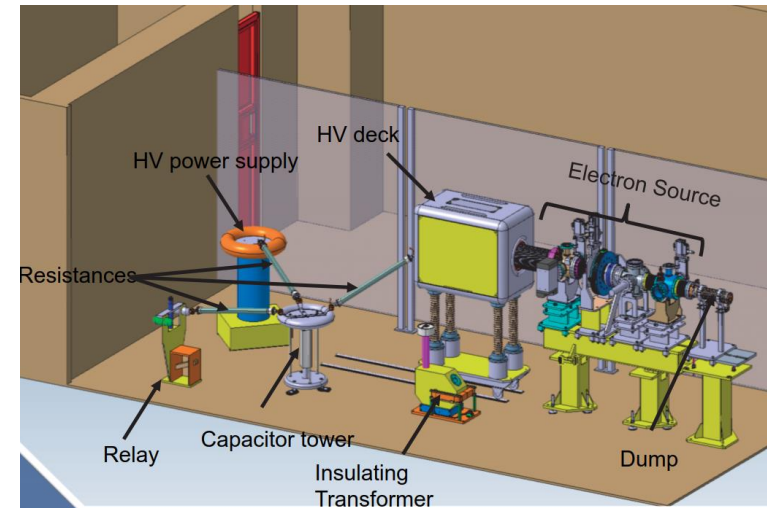


# Electron and Ion Sources

## CLIC Drive Beam Thermionic Gun



Cathode System



Test Stand

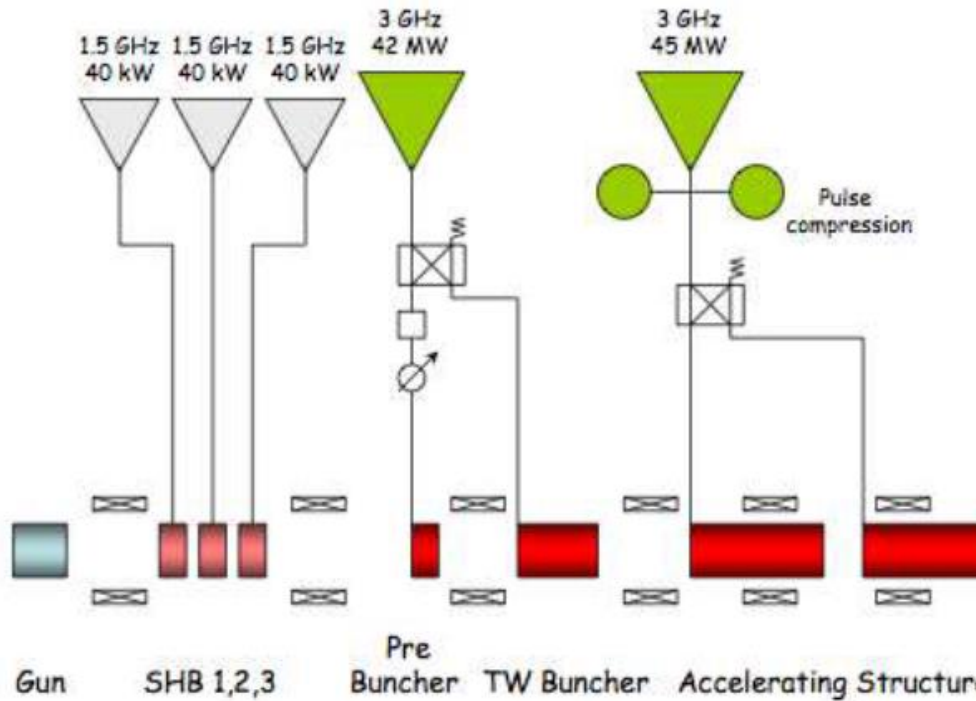
The CLIC Drive Beam Electron Gun is a Thermionic Gun.



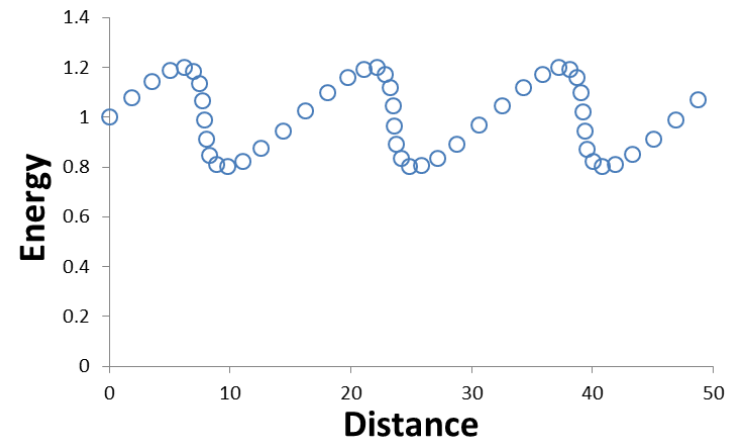


# Electron and Ion Sources

## CTF3 Thermionic Gun – bunching the beam



### RF bunching



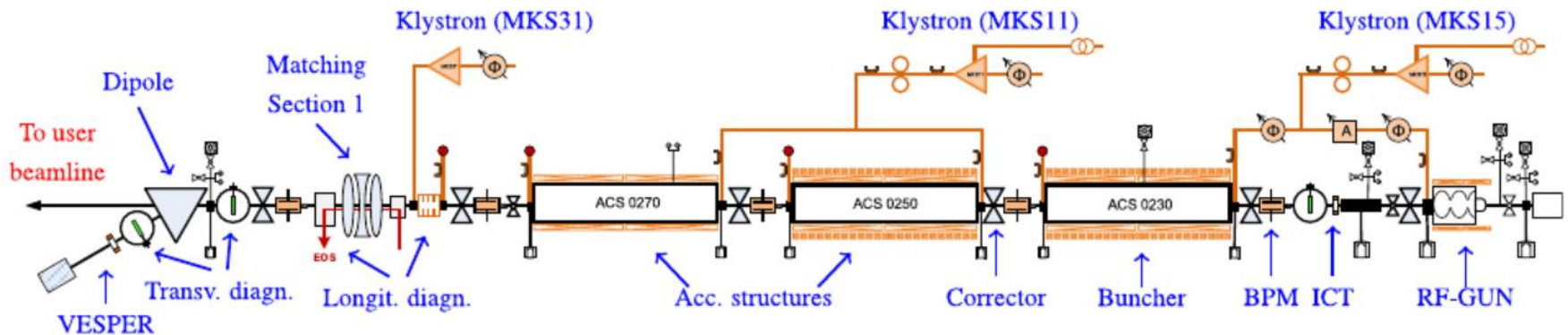
- The thermionic gun produces a 1.5 $\mu$ s pulse of electrons.
- RF cavities are then used to produce bunches, which can lead to transverse emittance growth.



# Electron and Ion Sources

## CLEAR – Electron Gun

CLEAR uses the PHIN Photo Cathode RF Gun.

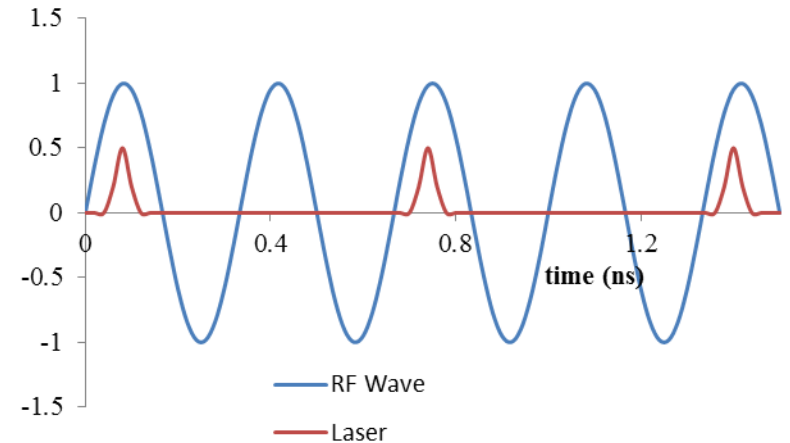
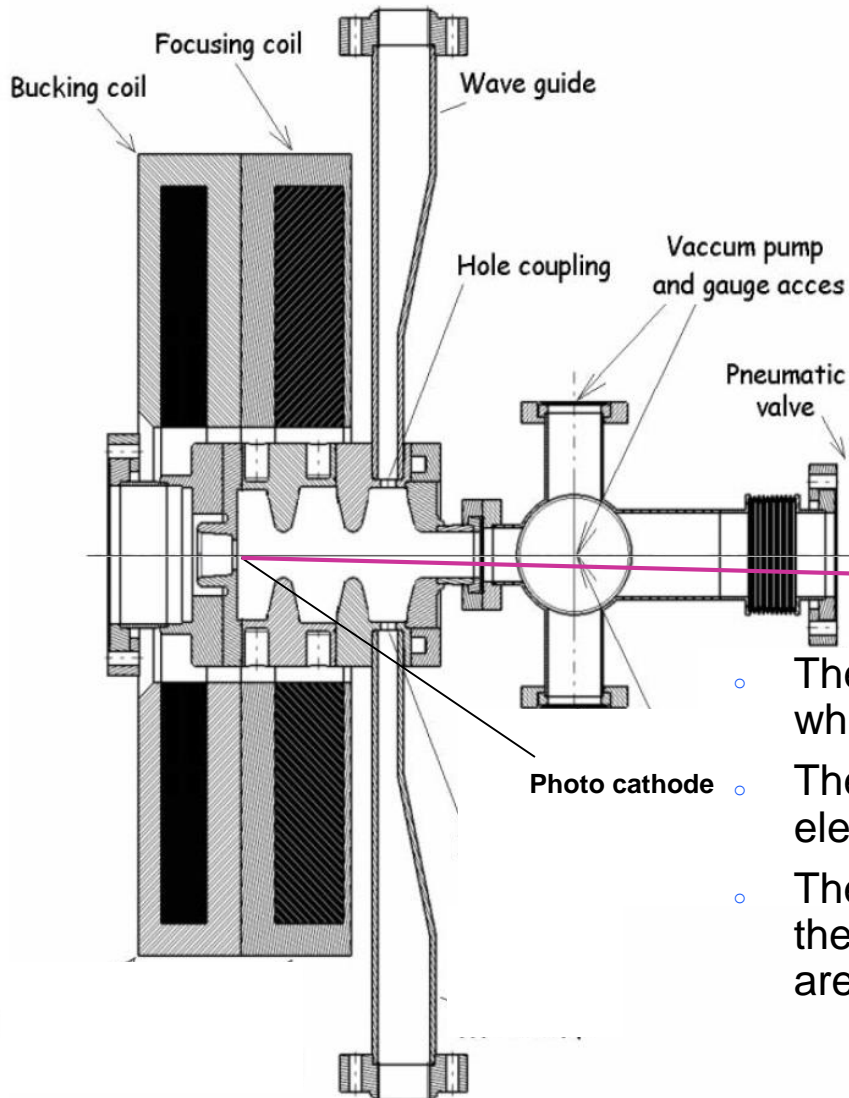


The CTF3 facility is now converted to CLEAR – as a facility for users. It uses a photo cathode RF gun for the electron source.



# Electron and Ion Sources

## CTF3 – CALIFES – probe beam photo gun



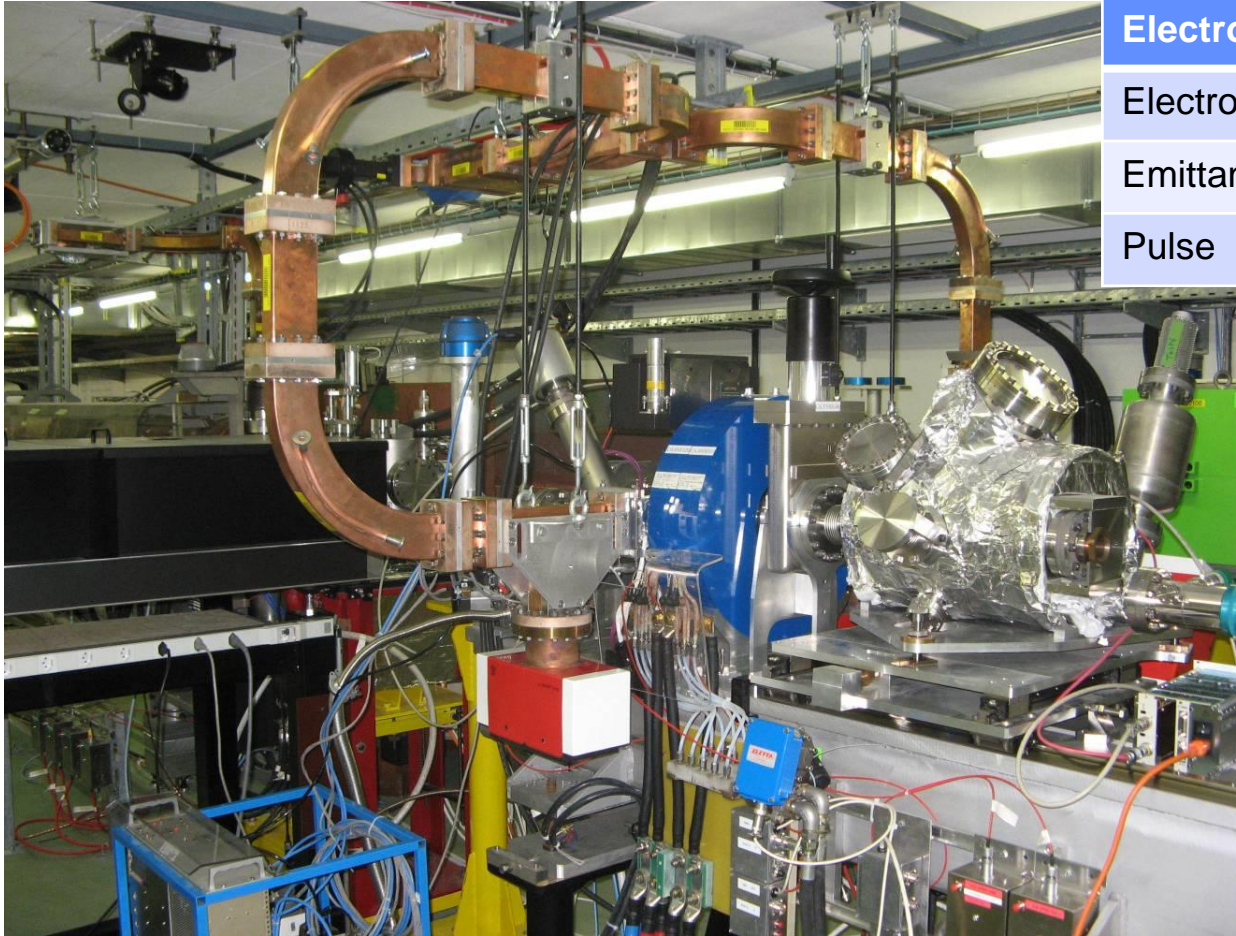
Nd:YLF – 4x frequency -> UV

- The RF gun accelerates to 5MeV in ~15cm, which combats space charge forces.
- The short laser pulses (~6ps) generate short electron bunches from the CsTe photo cathode.
- The laser can pulse at a different harmonic of the RF system. 1.5GHz laser-electron bunches are created, using RF 3GHz acceleration.



# Electron and Ion Sources

## CTF3 – CALIFES – RF Photo injector



Electron Current	0.9 A
Electron Energy	5-6 MeV
Emittance	20 mm.mrad
Pulse	150ns @ 5 Hz

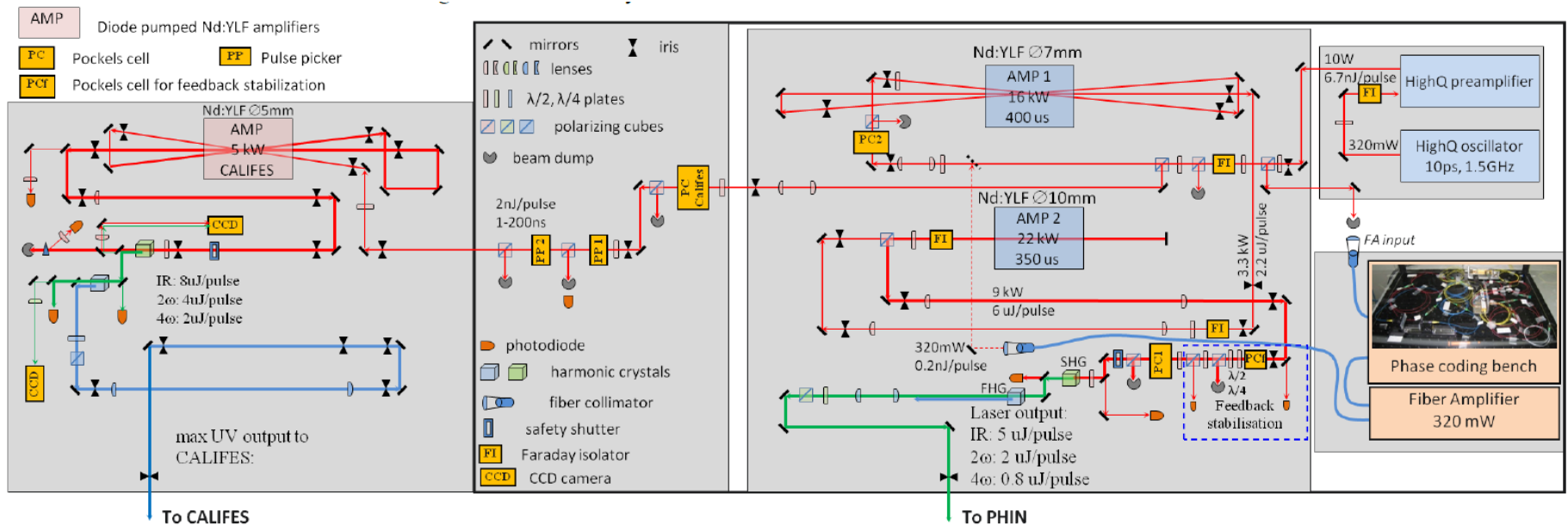




# Electron and Ion Sources

## CTF3 – Photo Emission

◆ ... and you need a laser...





# Electron and Ion Sources

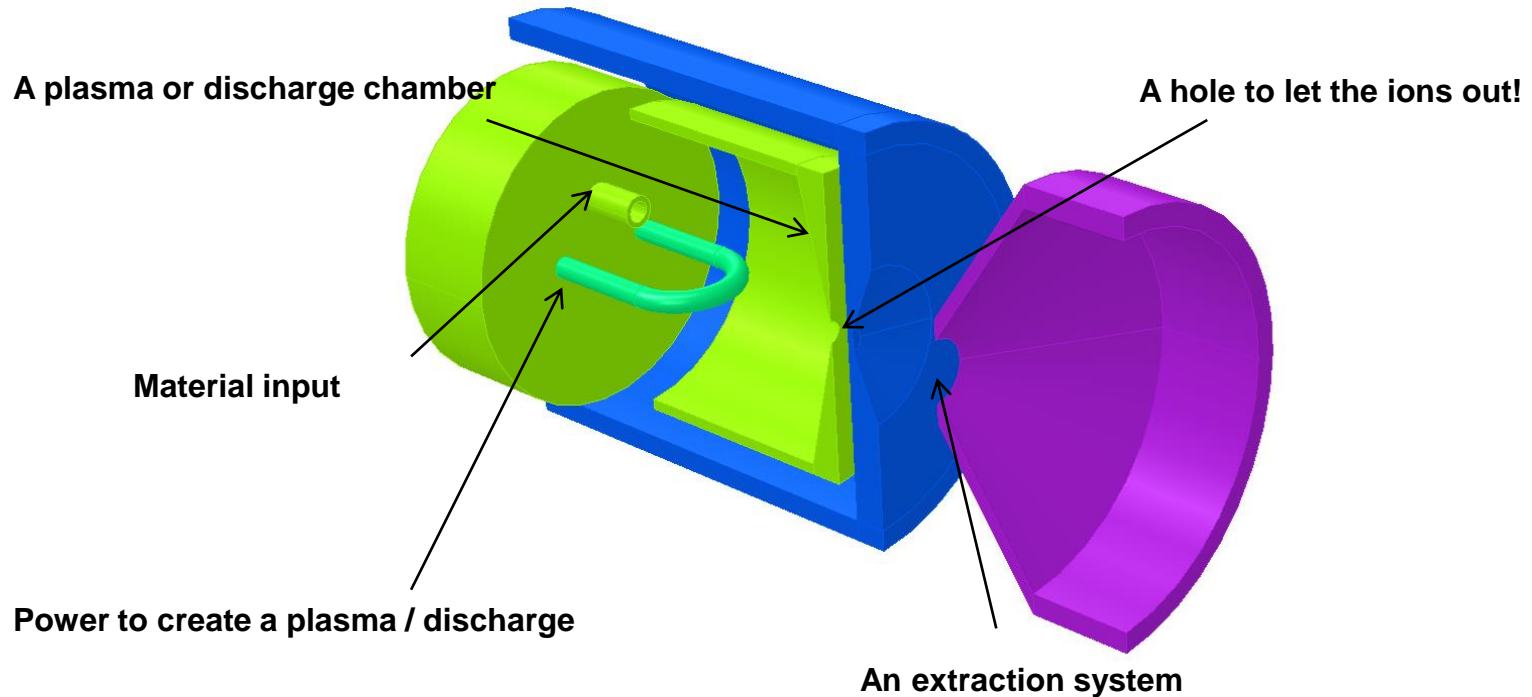
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# Electron and Ion Sources

## Ion Sources - Basics

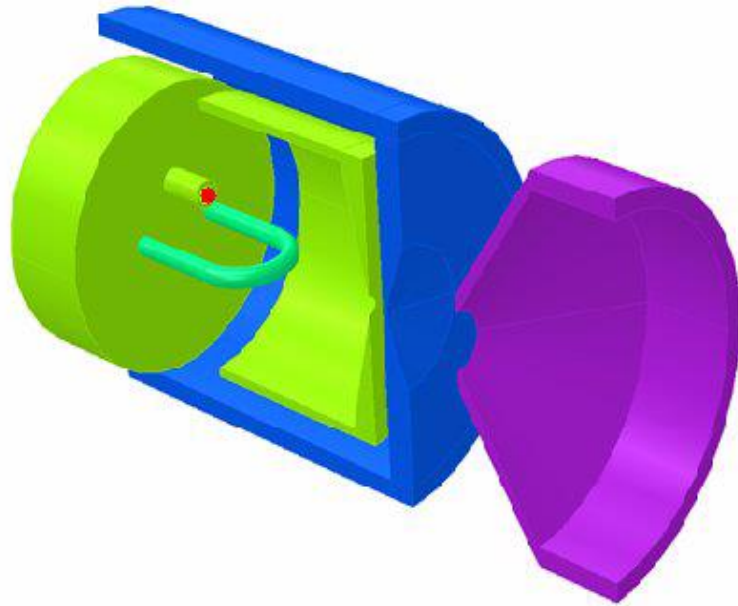
- ◆ An Ion Source requires an “ion production” region and an “ion extraction” system.
- ◆ In most (but not all) cases, ion production occurs in a plasma.





# Electron and Ion Sources

## Ion Sources - Basics

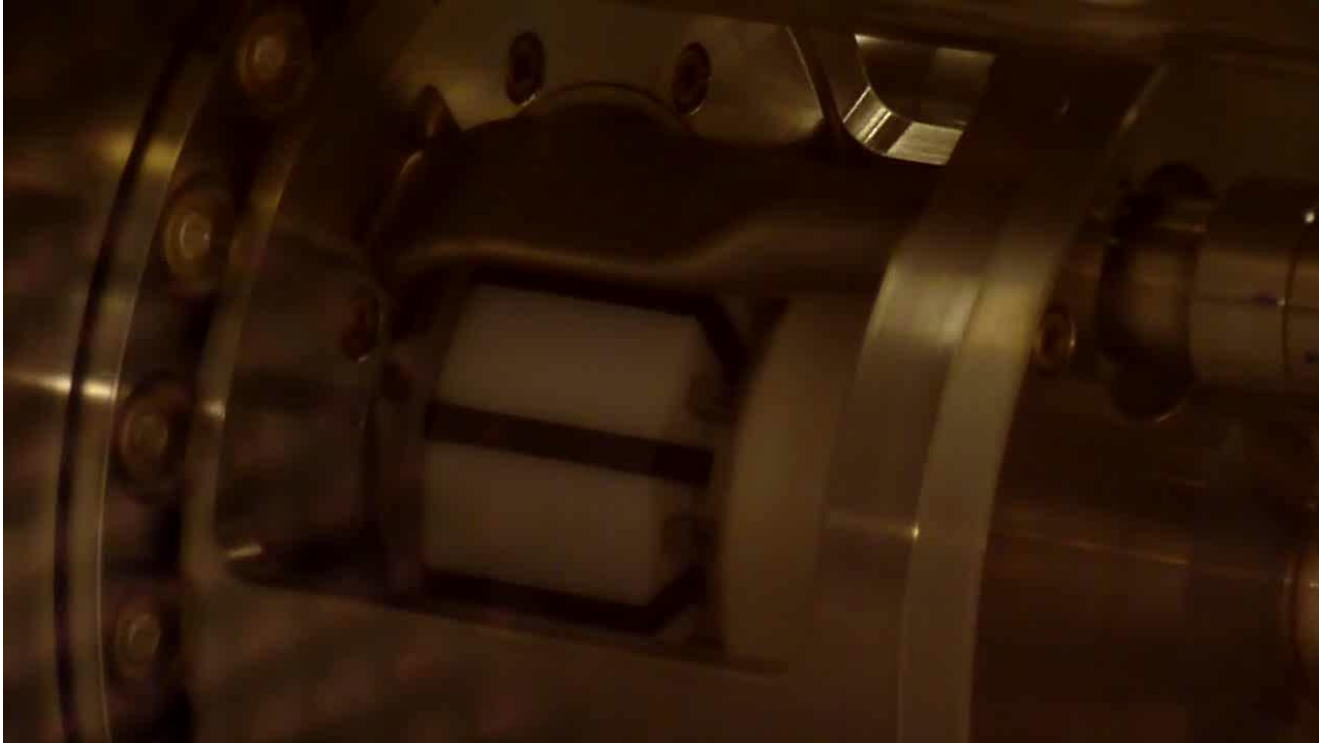






# Electron and Ion Sources

## Ion Sources - Basics



- Hydrogen plasma (for protons or H-) from an RF source.
- Hydrogen plasma emits a pink light from an atomic transition.



# Electron and Ion Sources

## Ion Sources - Basics

- Plasma Processes
  - Electron heating
  - Plasma confinement (electric and magnetic)
  - Collisions (e-e, e-i, i-e, i-i + residual gas)
  - Atomic processes (ionisation, excitation, disassociation, recombination)
  - Surface physics (coatings + desorption, e-emission)
  - Mechanical processes (chamber heating+cooling, erosion)
- Ion Source Goal -> Optimise these processes to produce the required ion type and pulse parameters.
- AND maximize reliability, minimize emittance, power and material consumption.



# Electron and Ion Sources

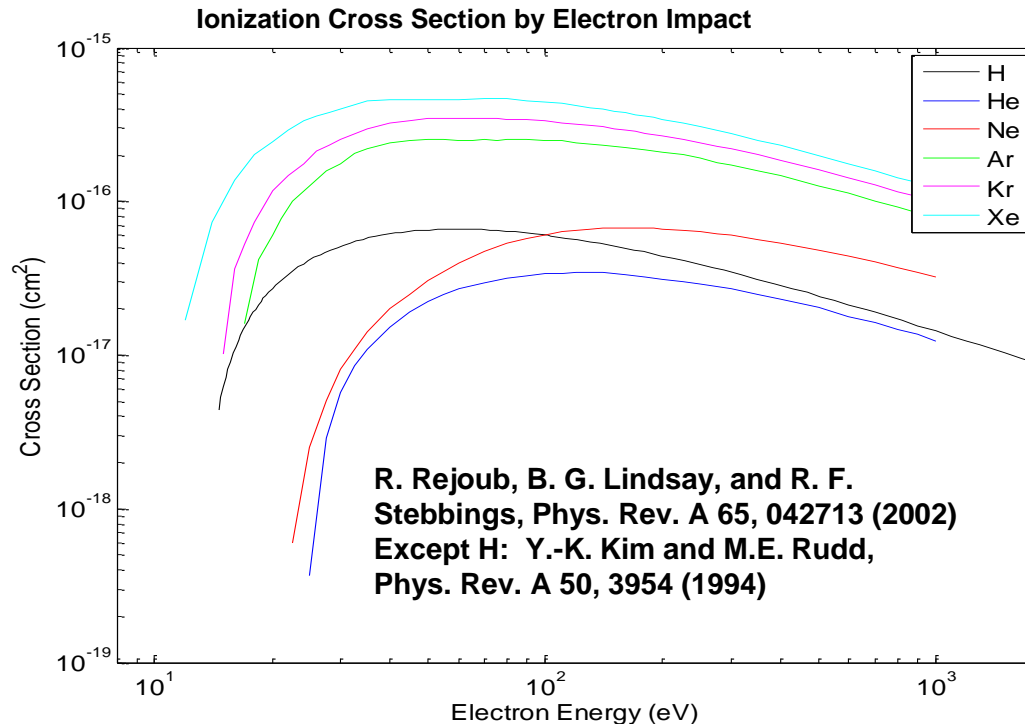
- **Electron Sources**
  - Thermionic
  - Photo-Cathodes
- **Ion Sources**
  - **Plasmas and their particle's motion**
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# Electron and Ion Sources

## The recipe for ions

- In many ion sources we use electron impact ionization.
- We need to create electrons, accelerate them to a few times the ionization potential of the material, and get them to interact with atoms.



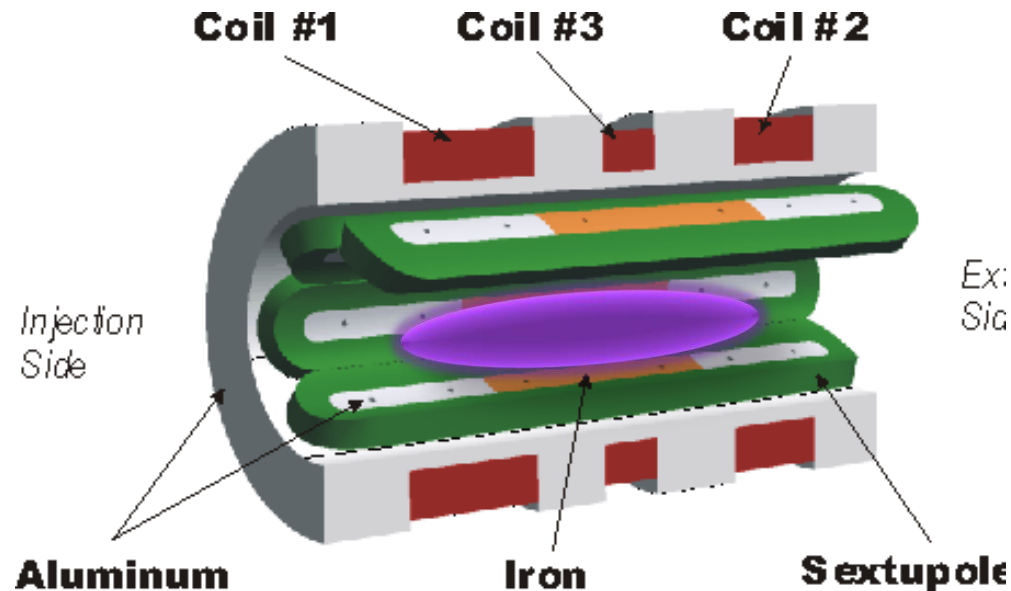
Some ion sources will use photo-ionization, or surface interactions.



# Electron and Ion Sources

## Controlling the ions

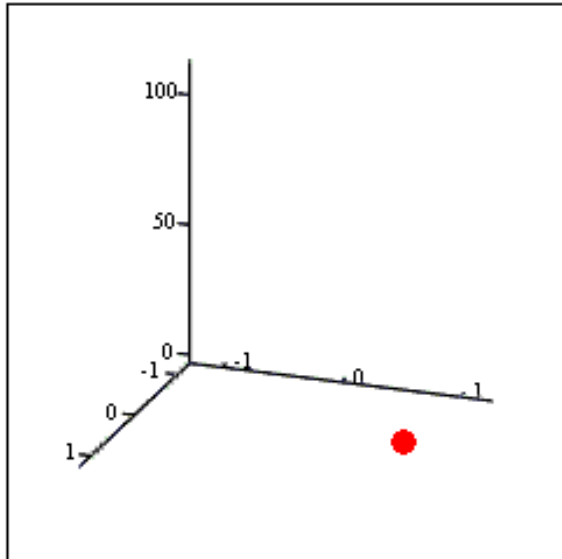
- In order to control the electrons and ions, we make use of magnetic and electric fields to alter their paths.



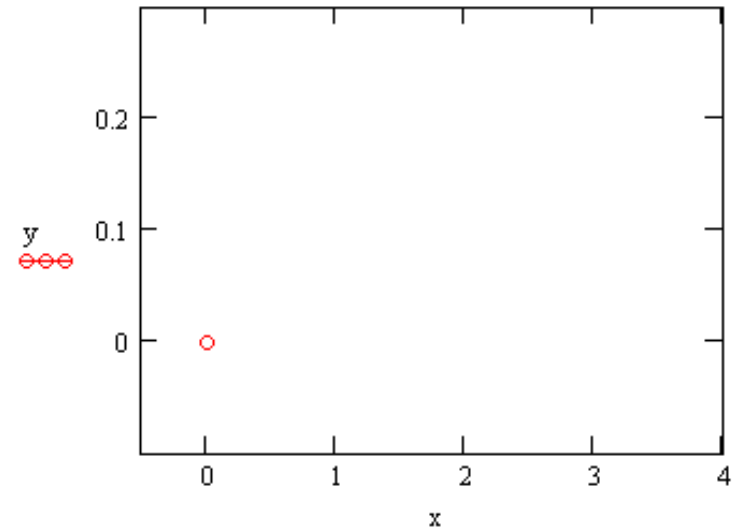


# Electron and Ion Sources

## Plasma Particle Motion



**B**



**E**

**B**

$$\rho_c = \frac{\sqrt{2mE_{\perp}}}{eB}, \omega_c = \frac{eB}{m}$$

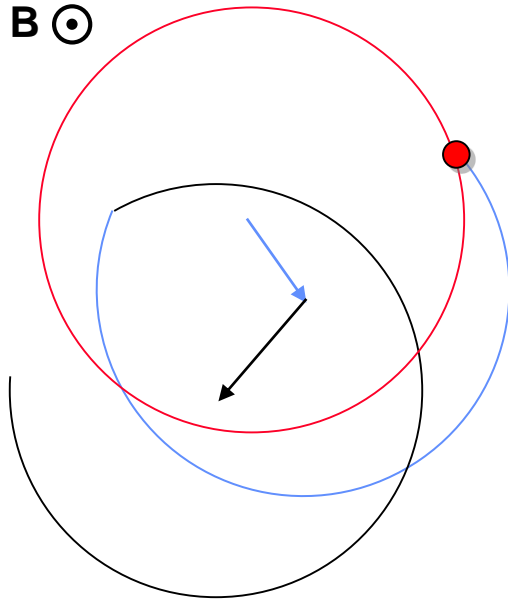
$$v_{drift} = \frac{\vec{E} \times \vec{B}}{B^2}$$



# Electron and Ion Sources

## Plasma Particle Motion

$\mathbf{B} \odot$



$$D \sim \rho_c^2 v_c \sim \left( \frac{\sqrt{2m_p E_\perp}}{eB} \right)^2 \frac{1}{T^{3/2}} \left( \frac{m_e}{m_p} \right)^{1/2} \sim \frac{m_p^{1/2}}{T^{1/2}}$$

**cf: opposite to classical  
energy – velocity equation !**

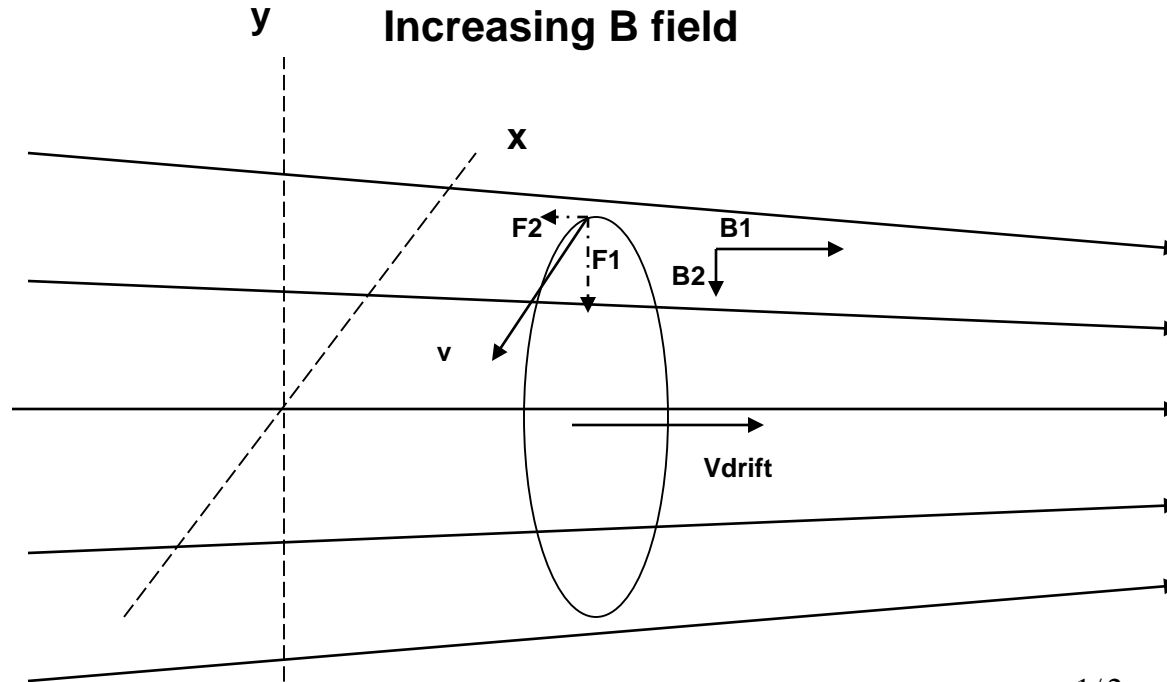
$$v = \left( \frac{2E}{m} \right)^{1/2}$$



# Electron and Ion Sources

## ECR Source – Magnetic Mirror

A force acts in the opposite direction to the  
Increasing B field



Energy is transferred  
from  $V_{drift}$  to  $V_{ecr}$

$$v_{drift} = \left\{ \frac{2}{m} (K - \mu B) \right\}^{1/2}$$

$$\mu = \frac{mv_{\perp}^2}{2B}$$

$\mu$  = magnetic moment

$K$  = total kinetic energy





# Electron and Ion Sources

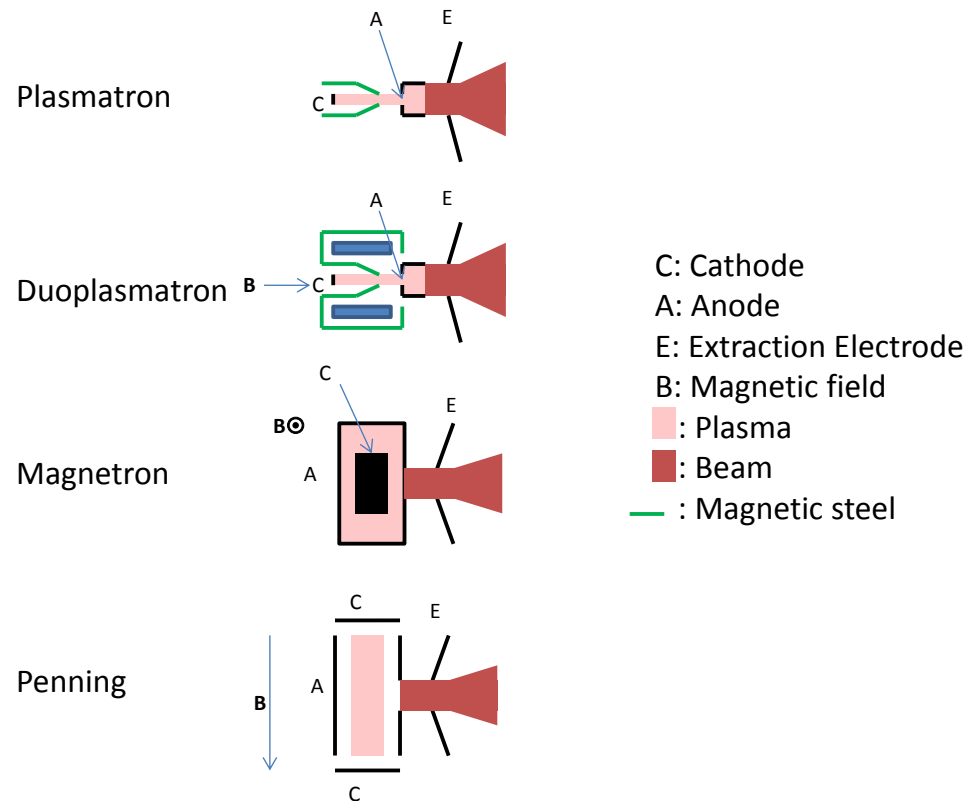
## Ion Source – Gas Discharge

- Many sources work on the principle of a cathode – anode gas discharge
- The gas can be a compound form (e.g. Carbon from CO) or from a vapour (e.g. lead vapour from an oven).
- Electrons from a hot cathode are accelerated into the gas by a cathode to anode voltage, and ionize the gas atoms/molecules with electron impact ionization.
- At low gas pressures, most electrons do not cause ionization and the ion density remains low.
- At higher pressures, the electrons cause ionization, which also leads to new electrons to be accelerated and cause ionization.



# Electron and Ion Sources

By applying an magnetic field, electrons can have longer path lengths inside the source, and the chance of ionization is increased.





# Electron and Ion Sources

## Ion Sources - Basics

- **Ion Sources at CERN.**
  - Linac2 – Protons - Dupolasmatron
  - Linac3 – Ions (Pb, O, Ar) – ECR
  - ISOLDE – Radioactive ions – Surface, laser, Electron Bombardment.
  - Linac4 – Negative Hydrogen – RF



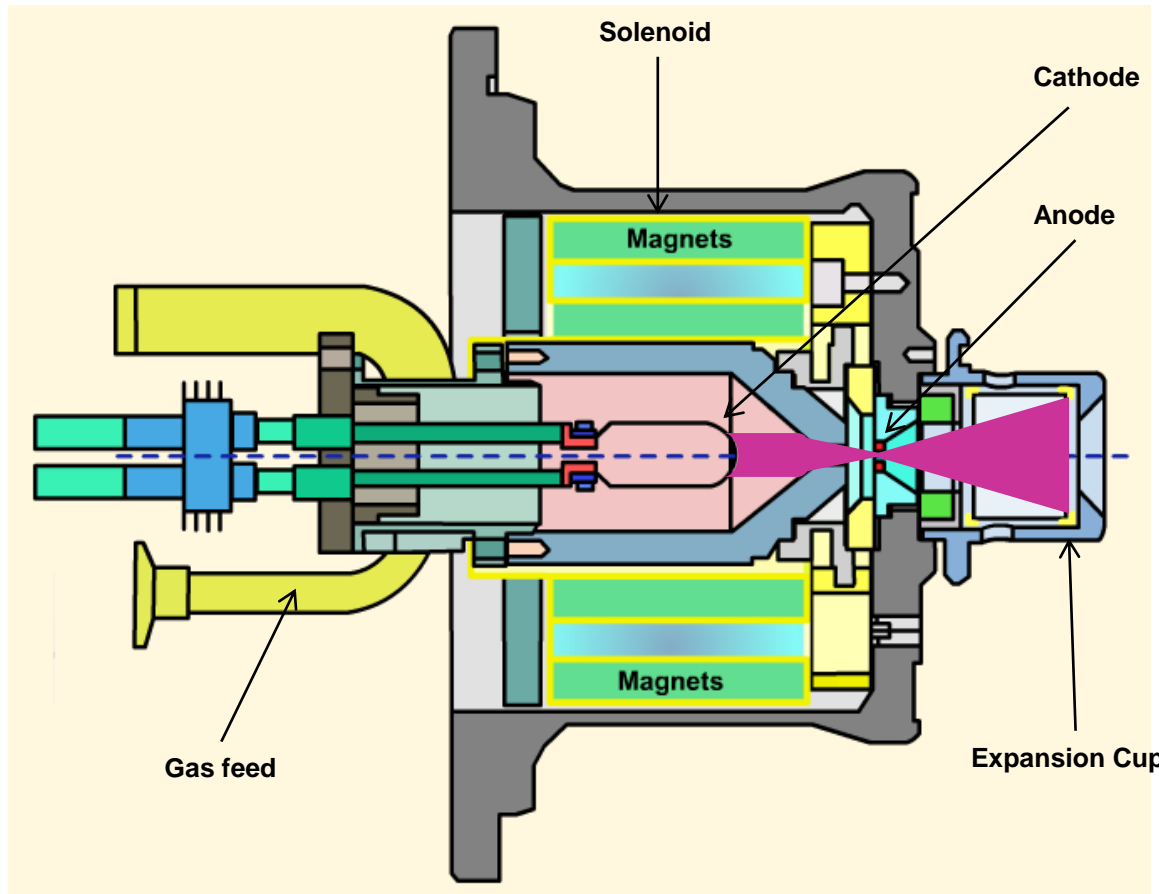
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# Electron and Ion Sources

## Ion Source – Duoplasmatron – Linac2



Proton Current	200 mA
Proton Energy	90 keV
Emittance	~0.4 mm.mrad
Pulse for LHC	20us @ 1 Hz
# protons / pulse	$2.5 \times 10^{13}$
# LHC bunches	~24 *

\* Creation of LHC bunches is a complicated process, this is an example for 50ns LHC bunches



# Electron and Ion Sources

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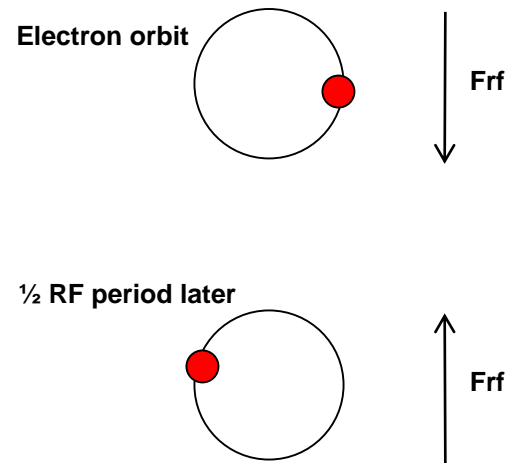
# Electron and Ion Sources

## Ion Source – ECR – Linac3

- Electron Cyclotron Resonance Ion Source (ECR)
  - For a given magnetic field, non-relativistic electrons have a fixed revolution frequency.
  - The plasma electrons will absorb energy at this frequency (just as particles in a cyclotron).
  - If confined in a magnetic bottle, the electrons can be heated to the keV and even MeV range.
  - Ions also trapped by the charge of the electrons, but for milli-seconds allowing multiple ionisation.
  - The solenoid magnetic field still allows losses on axis – these ions make the beam.

$$\omega_c = \frac{eB}{m}$$

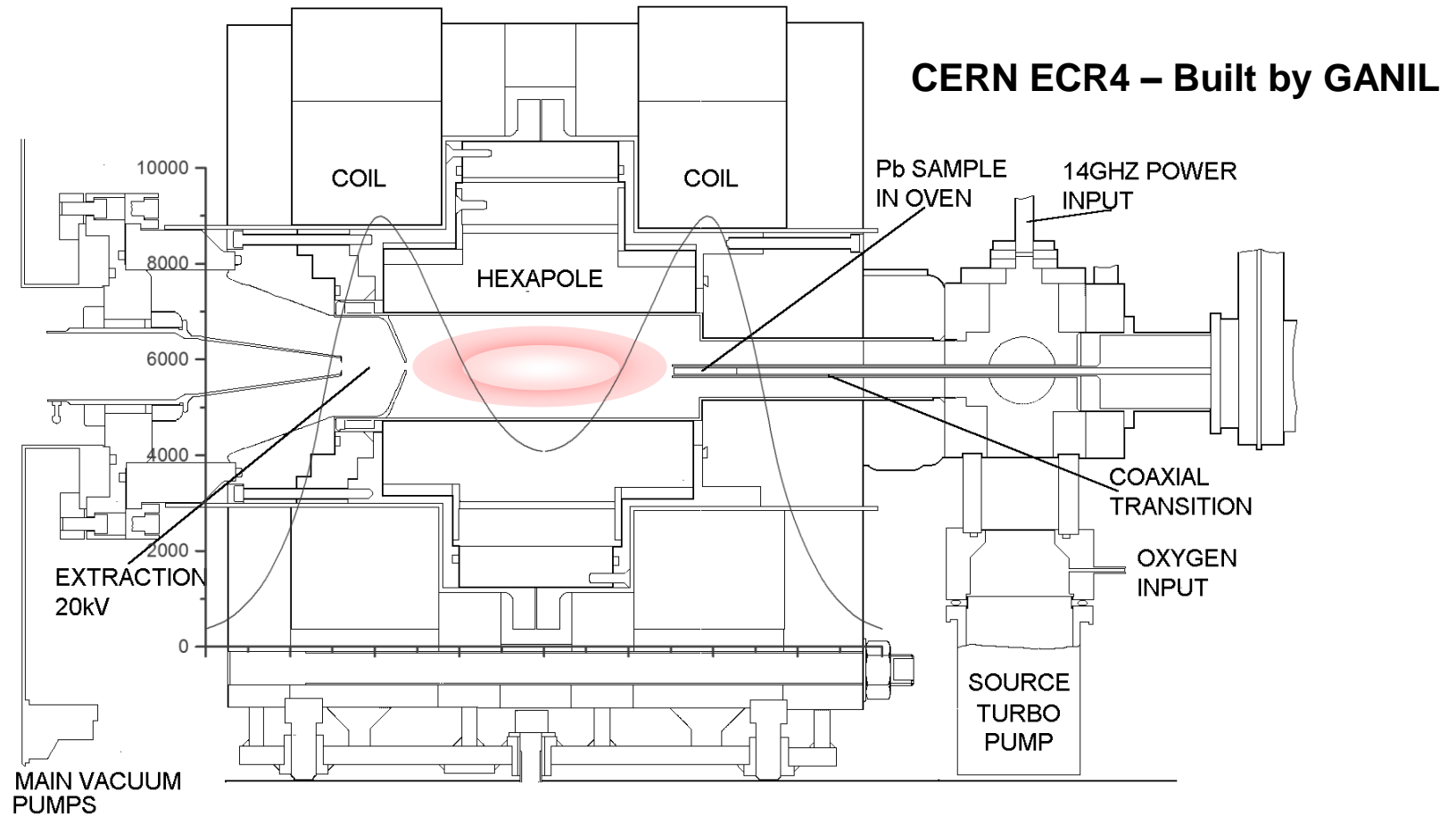
$$f_c [\text{GHz}] = 28 \times B[\text{T}]$$





# Electron and Ion Sources

## Ion Source – ECR



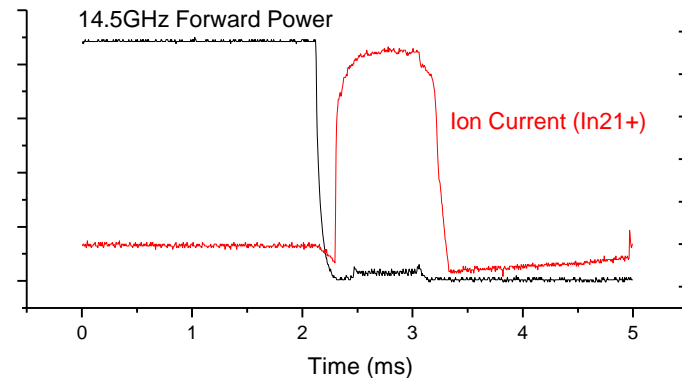
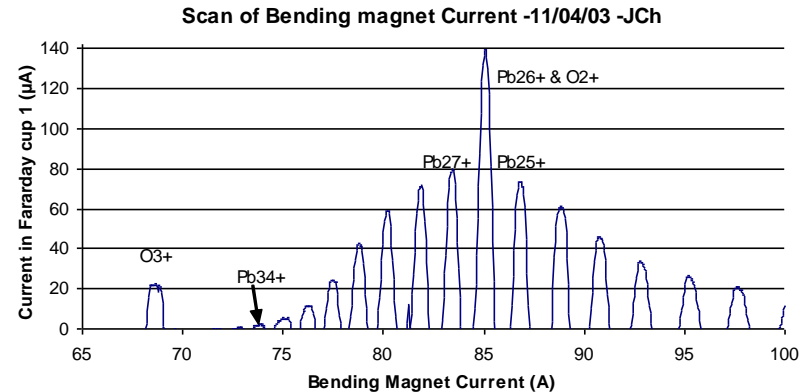




# Electron and Ion Sources

## Ion Source – ECR – High charge states

- No filament is needed, greatly increasing the source lifetime.
- Singly, multiply and highly charged ions can be produced by these sources (although the source construction will influence this).  
 $A \rightarrow A^+ \rightarrow A^{2+} \rightarrow A^{3+}$   
Stepwise ionisation.
- Gaseous ions are easily made. Metallic ions come from an OVEN or from a compound gas (e.g UF<sub>6</sub> for uranium).
- In the afterglow mode, the ion intensity increases AFTER switching off the micro-waves.

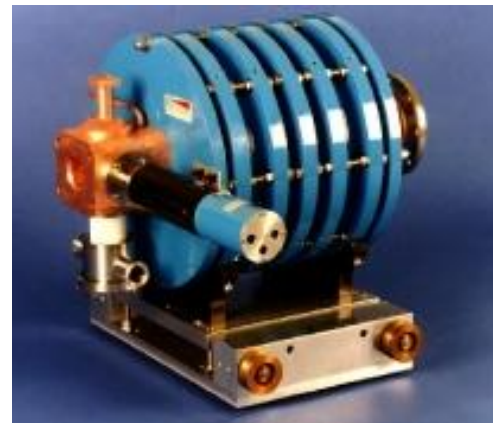
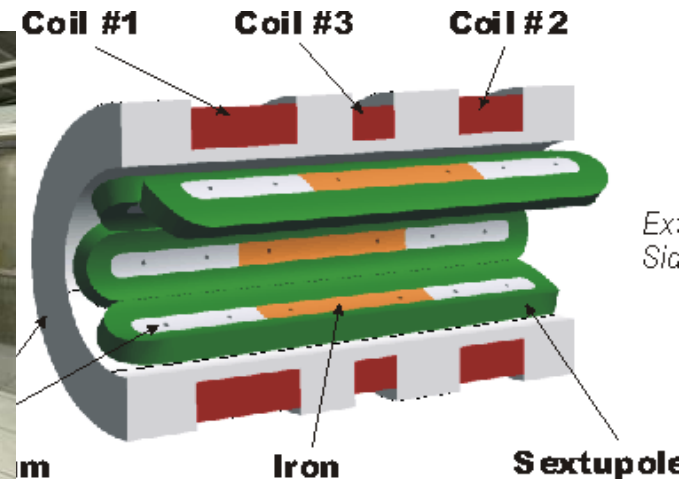




# Electron and Ion Sources

## Ion Source – ECR – High charge states + industry solutions

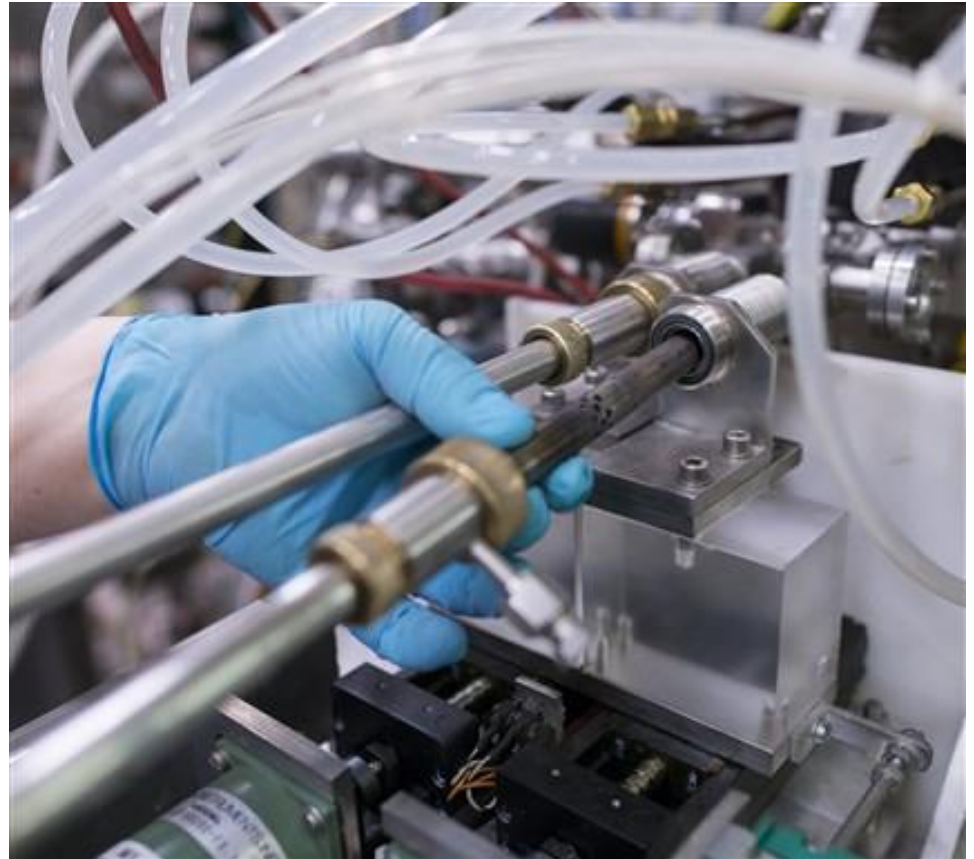
- Plasma density increases with frequency and associated magnetic field.
- Example: VENUS source and Berkeley, Ca, uses superconducting solenoid and sextapole magnets.
- Industry can now provide turnkey solutions for ECR ions sources, usually using permanent magnets.





# Electron and Ion Sources

**Lead (Pb) is evaporated from a micro oven in the source**





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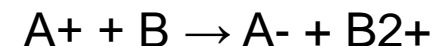
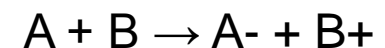
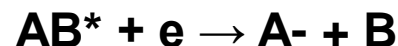
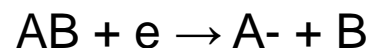
# Electron and Ion Sources

## Ion Sources – Negative Ions

- ◆ Negative ion sources allow:
  - Charge exchange injection into synchrotrons.
  - Charge exchange extraction from cyclotrons.
  - Tandem accelerators.

	Electron Affinity (eV)
H	0.7542
He	<0
Li	0.6182
Be	<0
B	0.277
C	1.2629
N	<0
O	1.462
F	3.399

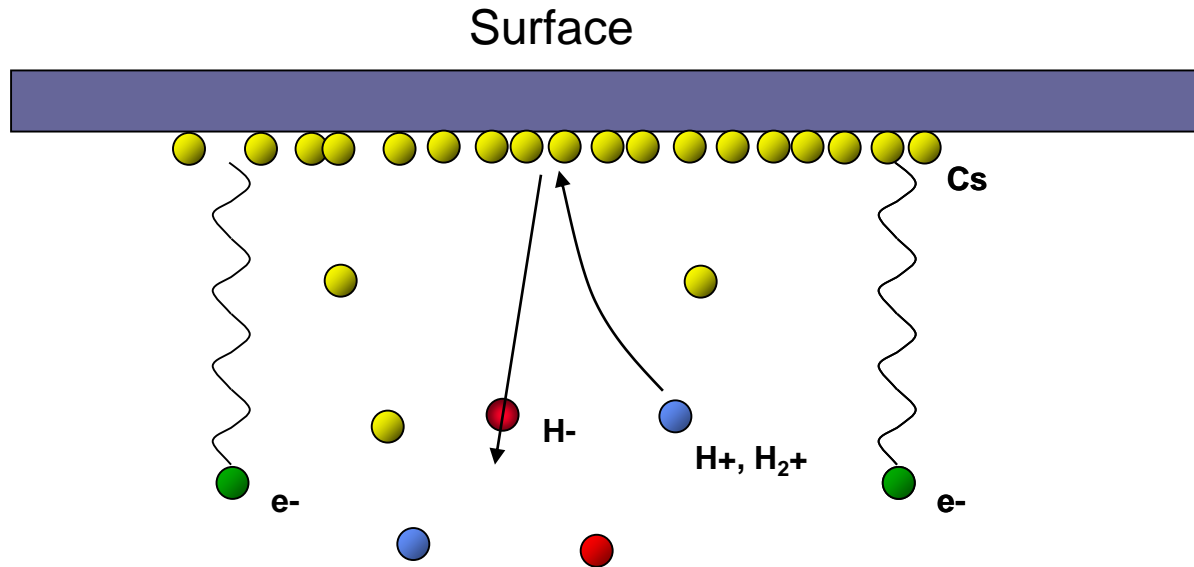
- ◆ The bonding energy for an electron onto an atom is the Electron Affinity.
- ◆  $E_a < 0$  for Noble Gases
- ◆ Large  $E_a$  for Halogens
- ◆ Two categories of negative ion sources
  - Surface – an atom on a surface can be desorbed with an extra electron (whose wave-function overlapped the atom).
  - Volume – Through collisions, e-capture and molecular dissociation, negative ions can be formed.





# Electron and Ion Sources

## H- Surface Ion Production



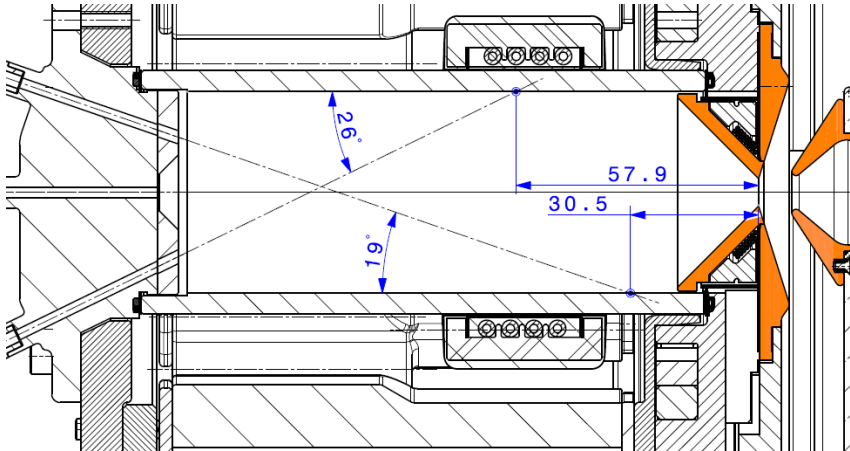
- Protons from the plasma are accelerated to the cathode, which has a coating of caesium.
- The protons desorbed from the low work function surface, with an additional electron.
- The plasma must not be too hot, to avoid ionising the H-.
- Penning, Magnetron, etc, sources produce H this way.



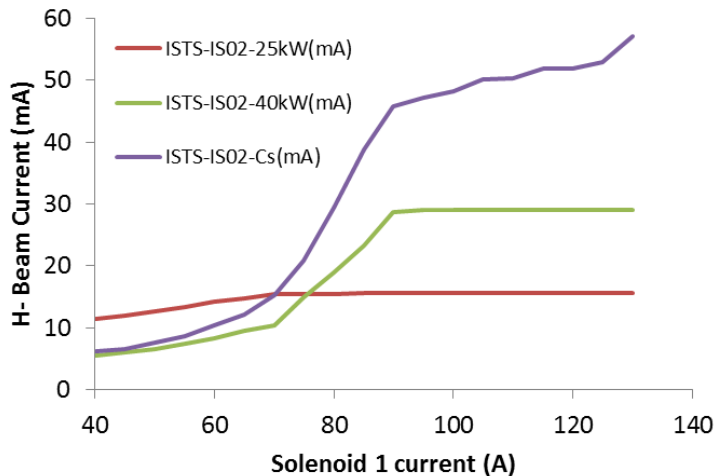


# Electron and Ion Sources

## Ion Sources – Negative Ions – Linac4



- Plasma is created using 2MHz RF in a solenoid coil.
- A surface near the extraction is coated with cesium, evaporated from an oven at the back of the source.
- The plasma protons strike the cesium surface and H<sup>-</sup> are emitted.



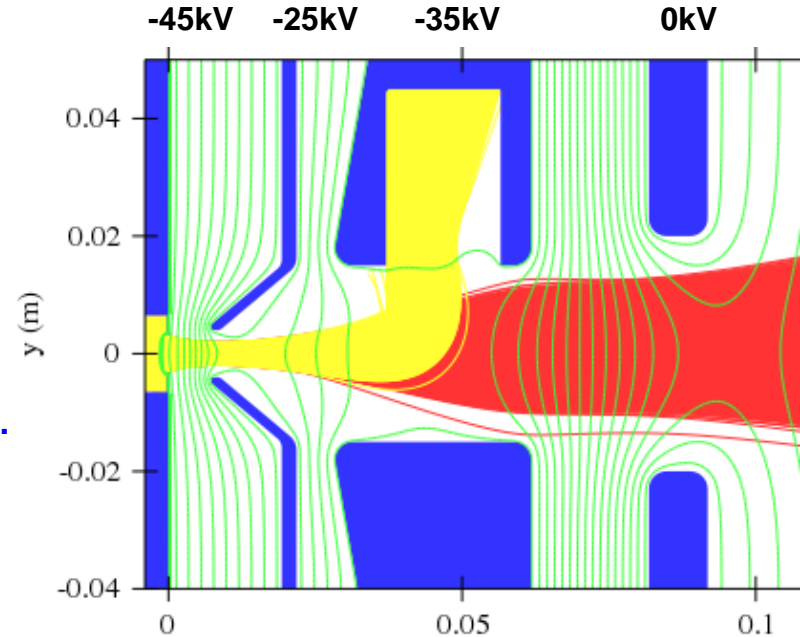
- Plot shows the beam current increasing as cesium is added to the Linac4 ion source.
- Estimation is a few tens of nm of Cs surface coating.



# Electron and Ion Sources

## Ion Sources – Negative Ions – Linac4

- Electrons (yellow) are extracted along with negative ions (red).
- Electrons can be separated with a dipole B field in extraction.
- In the Linac4 RF source (without cesium)  $>1\text{A}$  of electrons are extracted.







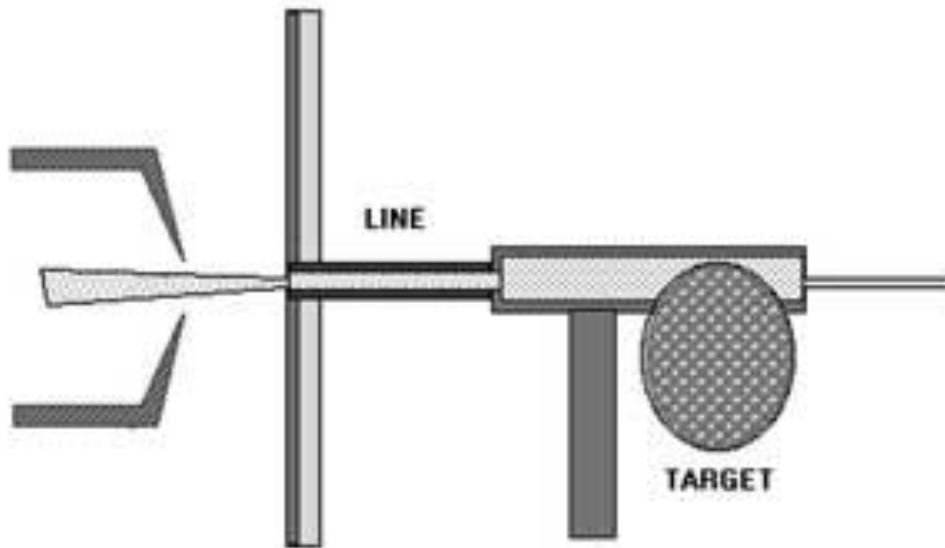
# Electron and Ion Sources

- **Electron Sources**
  - Thermionic
  - Photo-Cathodes
- **Ion Sources**
  - Particle motion in plasmas
  - Protons
  - ECR Ion Source
  - Negative Ions
  - **Radioactive Ions**



# Electron and Ion Sources

## Ion Source – Radioactive Ions – ISOLDE

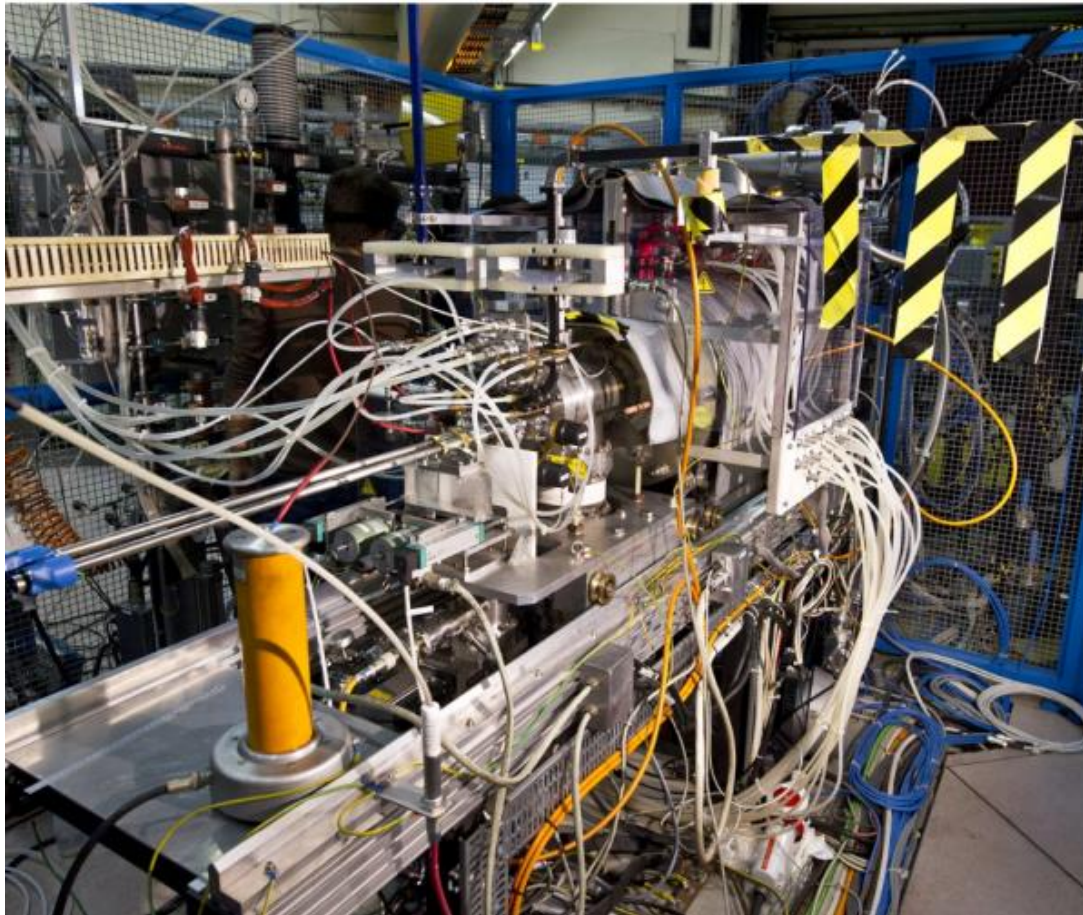


- ◆ A gas/vapour of new isotopes is produced from 1.4GeV protons onto a target.
- ◆ The ion source is used to ionize the gas.
- ◆ The ions will be mass selected in an ion spectrometer.

- ◆ An important goal is to have a high conversion rate of the desired gas to ions.
- ◆ The sources must be robust with the extreme radiation environment. For example minimize use of any organic compounds.
- ◆ The sources can help to reduce the contamination (i.e. stable/other isotopes of the same mass) through some selective process (e.g. using lasers to selectively ionize).



# Electron and Ion Sources



- ◆ For sources, all we have seen so far is the ion generation.
- ◆ You still have to add the high voltage systems, pumping, cooling, power convertors, controls...



# Electron and Ion Sources

## Summary

### ◆ Electron Source Summary

- Thermionic Source. Some thermal electrons are above the Work-Function.
- Use low work-function or high melting point materials to obtain the most electrons
- Photo-cathodes – Use photons above the work-function or  $E_g + E_a$ .
- Metals – Stable but have a low quantum efficiency
- Semiconductors – high Q, but can be unstable and degrade in use.

### ◆ Ion Source Summary

- Plasmas are a common production method for ions.
- There are many ways to produce, heat and confine a plasma, leading to many source types.
- CERN already uses quite an array of these types.



# Electron and Ion Sources

## Further Reading

- ◆ Handbook of Ion Source, B. Wolf, Boca Raton, FL: CRC Press, 1995
- ◆ Ion Sources, Zhang Hua Shun, Berlin: Springer, 1999.
- ◆ The Physics and Technology of Ion Source, I. G. Brown, New York, NY: Wiley, 1989
- ◆ Large Ion Beams: Fundamentals of Generation and Propagation, T. A .Forrester, New York, NY: Wiley, 1988
- ◆ CAS – 5<sup>th</sup> General School (CERN 94-01 ) and Cyclotrons, Linacs... (CERN-96-02 )



## **Electron and Ion Sources**

**Thank you for your attention.**



# Electron and Ion Sources

$A$ : Richardson-Dushman constant

$B$ : Magnetic field

$D$ : Diffusion rate

$E$ : Particle Kinetic Energy

$E$ : Electric field

$J$ : Current density

$m$ : Particle Mass

$n$ : Particle density

$T$ : Temperature

$U, V$ : Voltage

$v$ : Particle velocity

$v_{drift}$ : Particle drift velocity

$\beta$ : Relativistic beta

$\gamma$ : Relativistic gamma

$\phi_s$ : Work Function (Voltage)

$\nu$ : Collision Frequency

$\rho_c$ : Cyclotron Radius

$\omega_c$ : Cyclotron Frequency